

MILE POR AL SUBSET AND THE PROPERTY.

F.E. (Sem. – II) (Revised in 2007-08) Examination, May/June 2008 BASIC ELECTRONIC ENGINEERING

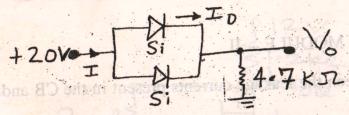
Duration: 3 Hours Max. Marks: 100

Instructions: 1) Attempt five questions, choosing at least one from each Module.

- 2) Assume any additional data, if necessary.
- 3) Graph papers will be provided on request.

MODULE - I

- 1. a) What is a diode and how is the depletion region formed?
 - b) Define Knee Voltage, Reverse Saturation Current, Peak Inverse Voltage and Reverse Breakdown Voltage for a diode.
 - c) Differentiate between Zener and Avalanche breakdowns.
 - d) With the help of diode circuit and necessary equations, explain how the Q-point is determined.
 - e) Determine I, V₀ and I_D for the given network.



- 2. a) A bridge rectifier uses load resistor $R_L = 2K\Omega$. Each diode has ideal characteristics with slope resistance $R_f = 10\Omega$. (Cut-in voltage is assumed to be zero). Input voltage V_i in each half cycle has amplitude of 20 volts and frequency is 50 Hz. Calculate:
 - i) Peak, dc and rms values of load current nonsing to a simil out one leaf W
 - ii) DC output voltage and dc output power required to the proper operation of the necessary conditions required to be intriled for the proper operation of
 - iii) TuF.

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